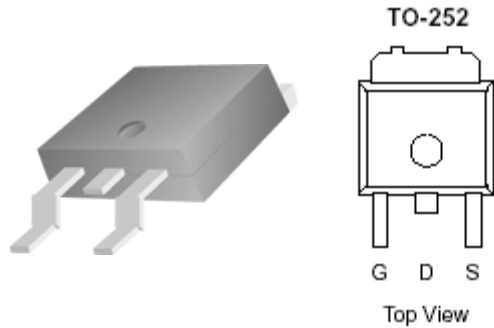


N-Channel 80-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ m(Ω)	I_D (A)
80	82 @ $V_{GS} = 10V$	21
	110 @ $V_{GS} = 4.5V$	18

- Low $r_{DS(on)}$ provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe DPAK saves board space
- Fast switching speed
- High performance trench technology



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ UNLESS OTHERWISE NOTED)			
Parameter	Symbol	Limit	Units
Drain-Source Voltage	V_{DS}	80	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current ^a	$T_C=25^\circ C$ I_D	21	A
Pulsed Drain Current ^b	I_{DM}	40	
Continuous Source Current (Diode Conduction) ^a	I_S	30	A
Power Dissipation ^a	$T_C=25^\circ C$ P_D	50	W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 175	$^\circ C$

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient ^a	$R_{\theta JA}$	50	$^\circ C/W$
Maximum Junction-to-Case	$R_{\theta JC}$	3.0	$^\circ C/W$

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

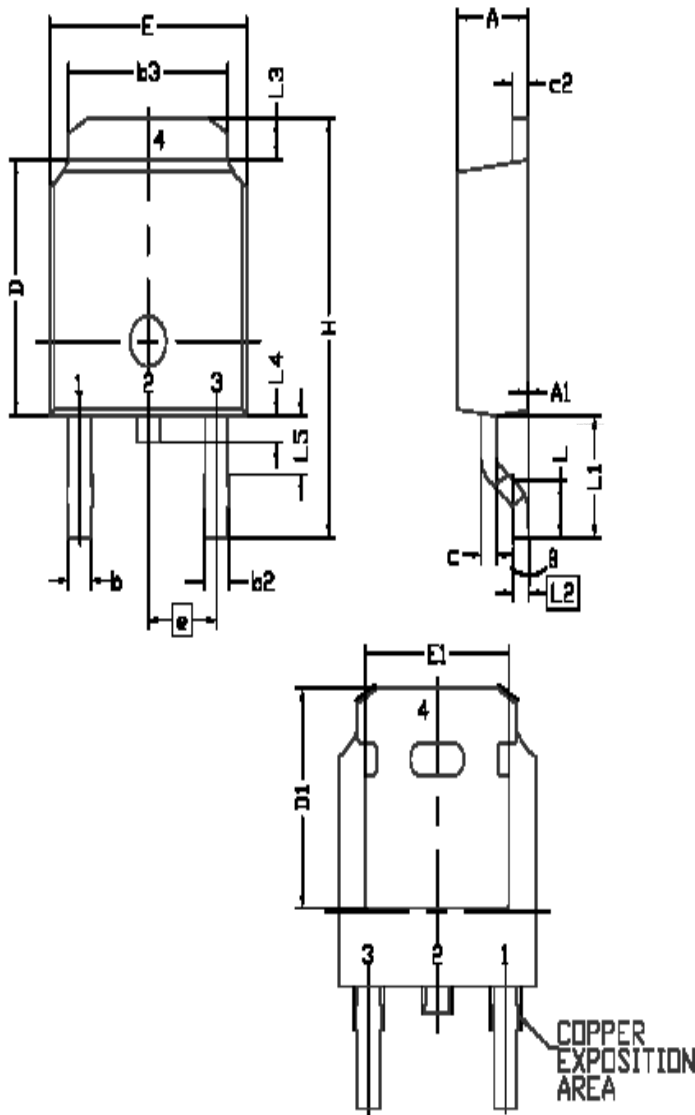
SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Conditions	Limits			Unit
			Min	Typ	Max	
Static						
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 uA	1.0			V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = 20 V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 64 V, V _{GS} = 0 V			1	uA
		V _{DS} = 64 V, V _{GS} = 0 V, T _J = 55°C			25	
On-State Drain Current ^A	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	34			A
Drain-Source On-Resistance ^A	r _{DS(on)}	V _{GS} = 10 V, I _D = 1 A			82	mΩ
		V _{GS} = 4.5 V, I _D = 1 A			110	
Forward Transconductance ^A	g _{fs}	V _{DS} = 40 V, I _D = 5.5 A		4.4		S
Diode Forward Voltage	V _{SD}	I _S = 9 A, V _{GS} = 0 V		1.1		V
Dynamic^b						
Total Gate Charge	Q _g	V _{DS} = 25 V, V _{GS} = 10 V, I _D = 9 A		19		nC
Gate-Source Charge	Q _{gs}			3		
Gate-Drain Charge	Q _{gd}			9.5		
Turn-On Delay Time	t _{d(on)}	V _{DD} = 100 V, R _L = 25 Ω, I _D = 9 A, V _{GEN} = 10 V		25		nS
Rise Time	t _r			60		
Turn-Off Delay Time	t _{d(off)}			65		
Fall-Time	t _f			45		

Notes

- a. Pulse test: PW ≤ 300us duty cycle ≤ 2%.
- b. Guaranteed by design, not subject to production testing.

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Package Information



SYMBOL	DIMENSIONAL REQMTS		
	MIN	NOM	MAX
E	6.40	6.60	6.731
L	1.40	1.52	1.77
L1	2.743 REF		
L2	0.508 BSC		
L3	0.89	—	1.27
L4	0.64	—	1.01
L5	—	—	—
D	6.00	6.10	6.223
H	9.40	10.00	10.40
b	0.64	0.76	0.88
b2	0.77	0.84	1.14
b3	3.21	3.34	3.46
e	2.286 BSC		
A	2.20	2.30	2.38
A1	0	—	0.127
c	0.45	0.50	0.60
c2	0.45	0.50	0.58
D1	5.30	—	—
E1	4.40	—	—
B	0°	—	10°